DESCRIPTION

The SPN1443 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

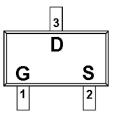
APPLICATIONS

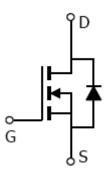
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

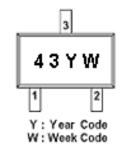
- 30V/2.8A, RDS(ON)= $65m\Omega@VGS=10V$
- 30V/2.3A, RDS(ON)= $90m\Omega@VGS=4.5V$
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ SOT-323 (SC-70) package design

PIN CONFIGURATION (SOT-323; SC-70)





PART MARKING





PIN DESCRIPTION					
Pin	Symbol	Description			
1	G	Gate			
2	S	Source			
3	D	Drain			

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN1443S32RGB	SOT-323	43YW

[★] Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

X SPN1443S32RGB : Tape Reel ; Pb – Free; Halogen – Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate –Source Voltage		VGSS	±20	V	
	TA=25°C	I.	2.8	•	
Continuous Drain Current(TJ=150°C)	Ta=70°C	- Id	2.3	A	
Pulsed Drain Current		Ідм	10	А	
Continuous Source Current(Diode Conduction)		Is	1.25	А	
Denne Dissingtion	Ta=25°C	D	0.33	W	
Power Dissipation	Ta=70°C	- Pd	0.21	W	
Operating Junction Temperature		TJ	150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		Rөја	100	°C/W	

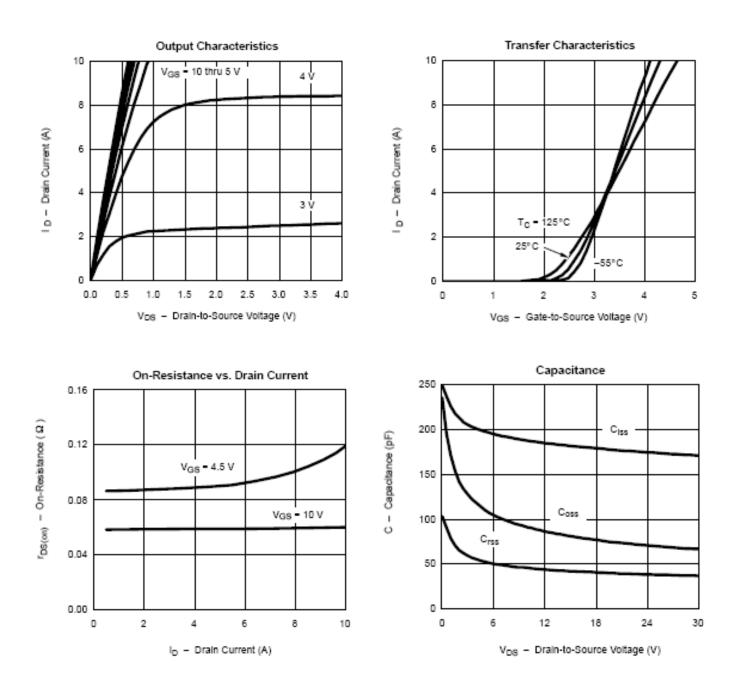


ELECTRICAL CHARACTERISTICS

(TA= 25° C Unless otherwise noted)

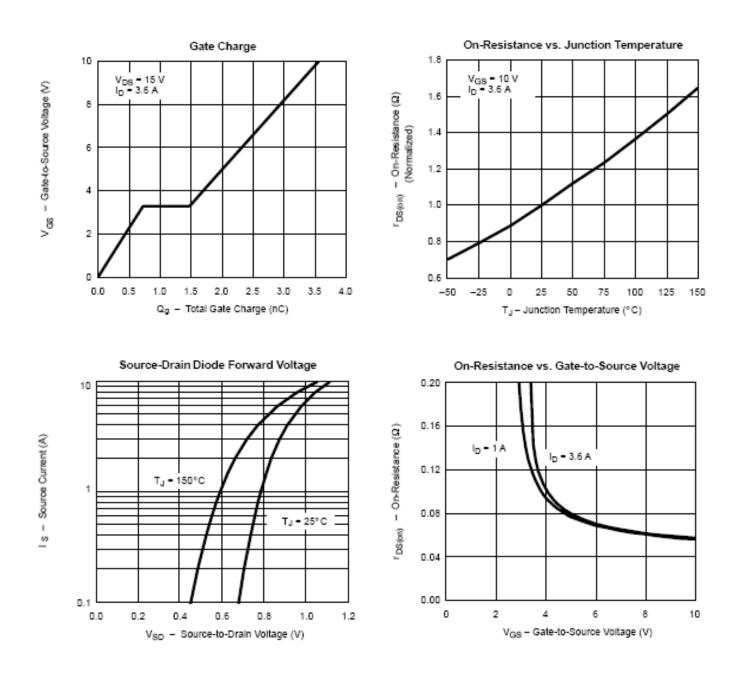
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static			•			
Drain-Source Breakdown Voltage	V(BR)DSS	Vgs=0V,Id=250uA	30			v
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	1.0		3.0	v
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA
Zero Gate Voltage Drain Current		VDS=30V,VGS=1.0V			1	uA
	Idss	Vds=30V,Vgs=0.0V Tj=55°C			10	
On-State Drain Current	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 10V$	6			A
	ID(00)	$V_{DS} \ge 4.5V, V_{GS} = 4.5V$	4			
Drain-Source On-Resistance	RDS(on)	$\frac{V_{GS} = 10V, ID = 2.8A}{V_{GS} = 4.5V, ID = 2.3A}$		0.050	0.065	Ω
Forward Transconductance	gfs	VDS=4.5V,ID=2.8A		4.6	0.090	S
Diode Forward Voltage	VSD	Is=1.25A,VGs=0V		0.82	1.2	V
Dynamic			•			
Total Gate Charge	Qg			4.5	10	nC
Gate-Source Charge	Qgs	$V_{DS}=15V_{GS}=10V$ $I_{D}=2.5$		0.8		
Gate-Drain Charge	Qgd	10-2.5		1.0		
Input Capacitance	Ciss			240		pF
Output Capacitance	Coss	VDS=15VGS=0V f=1MHz		110		
Reverse Transfer Capacitance	Crss			17		
Turn-On Time	td(on)			8	20	- ns
	tr	VDD=15RL=15		12	30	
Turn-Off Time	td(off)	$ID \equiv 1.0A, VGEN = 10$ RG=6 Ω		17	35	
	tf			8	20	

TYPICAL CHARACTERISTICS

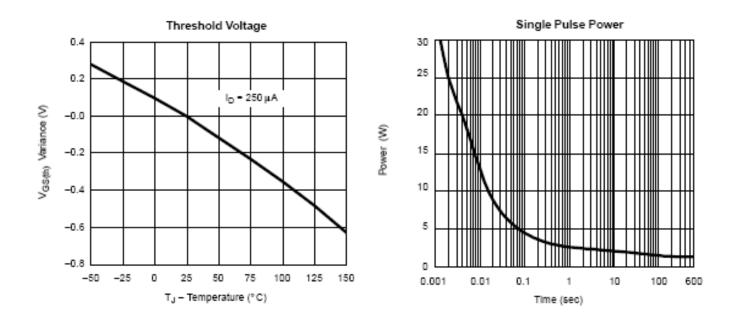


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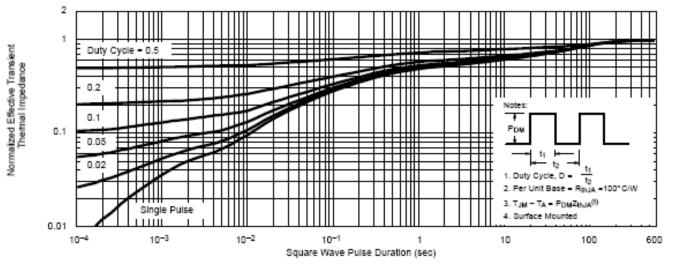
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

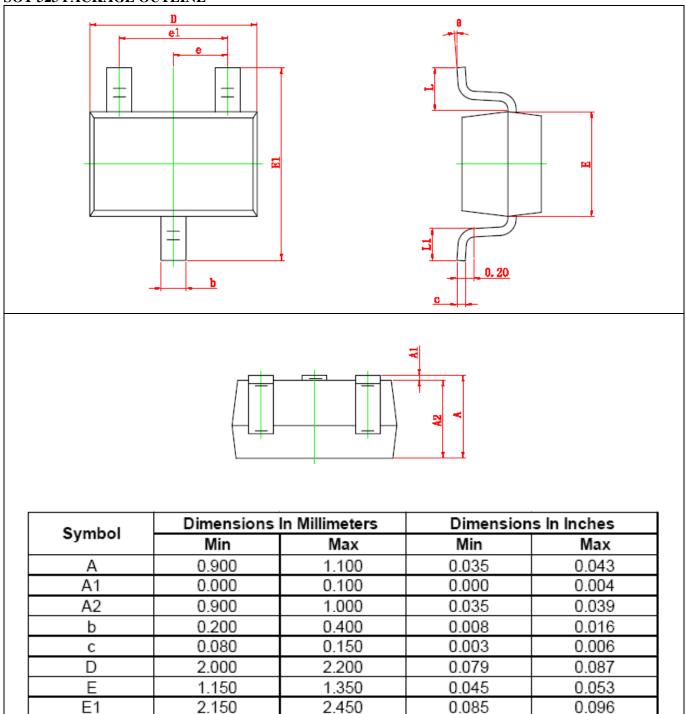


Normalized Thermal Transient Impedance, Junction-to-Ambient





SOT-323 PACKAGE OUTLINE



0.650 TYP

0.525 REF

1.400

0.460

8°

1.200

0.260

0°

е

e1

L

L1

θ

0.055

0.018

8°

0.026 TYP

0.021 REF

0.047

0.010

0°



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